

Overview

Flange Termination 250 Watts, 50Ω



Description

The G250N50W4 is high performance Aluminum Nitride (AIN) flange mount termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power combiners. The termination is also RoHS compliant!

General Specifications

Resistive Element Thick Film
Substrate AIN Ceramic

Mounting Flange Copper, nickel plated per QC-N-290

Operating Temperature -55°C to +150°C (see de-rating chart)

Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. All dimensions in inches.

Features:

- RoHS Compliant
- 250 Watts
- DC 2.2 GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

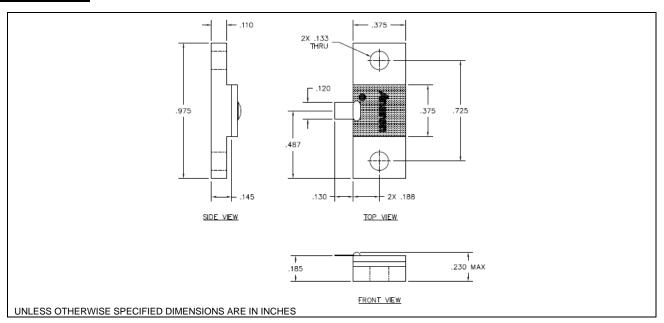
Electrical Specifications

Resistance Value:50 Ohms, \pm 2%Power:250 WattsFrequency Range:DC - 2.2GHz

Return Loss >20dB, DC to 2.2GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change with out notice.**

Outline Drawing

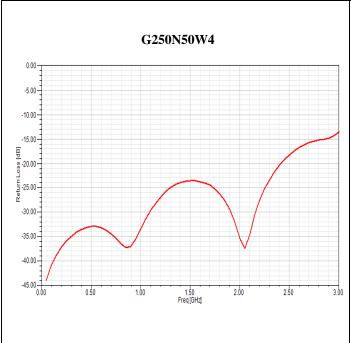


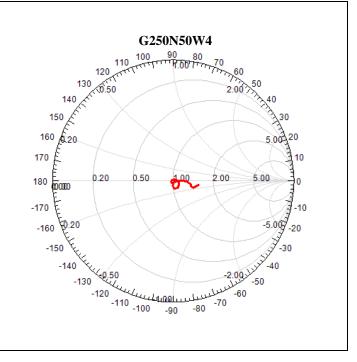


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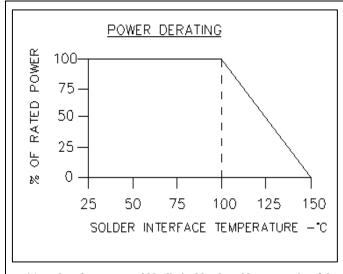


Typical Performance:



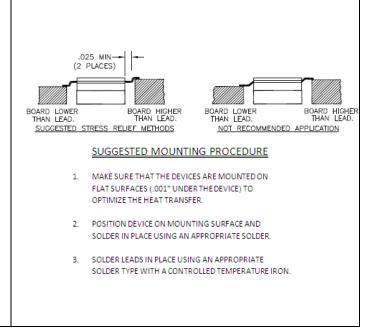


Power De-rating:



*Actual performance could be limited by the solder properties of the application

Mounting Footprint and Procedure:





Mouser Electronics

Authorized Distributor

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Anaren:
G250N50W4